

TRIPLE DIFFUSED PLANER TYPE
HIGH VOLTAGE, HIGH SPEED SWITCHING

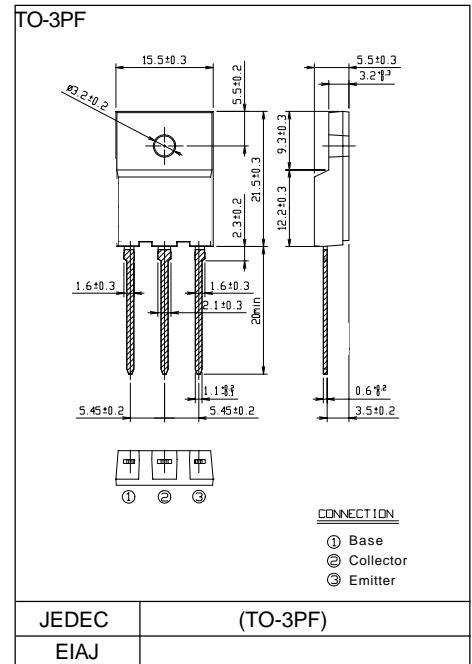
Features

- High voltage, high speed switching
- Low saturation voltage
- High reliability

Applications

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

Outline Drawings



Maximum ratings and characteristic

Absolute maximum ratings (T_c=25°C unless otherwise specified)

Item	Symbol	Rating	Unit
Collector-Base voltage	V _{CB0}	500	V
Collector-Emitter voltage	V _{CE0}	400	V
Emitter-Base voltage	V _{EB0}	7	V
Collector current	I _C	15	A
Base current	I _B	5	A
Collector power dissipation	P _C	80	W
Operating junction temperature	T _j	+150	°C
Storage temperature	T _{stg}	-55 to +150	°C

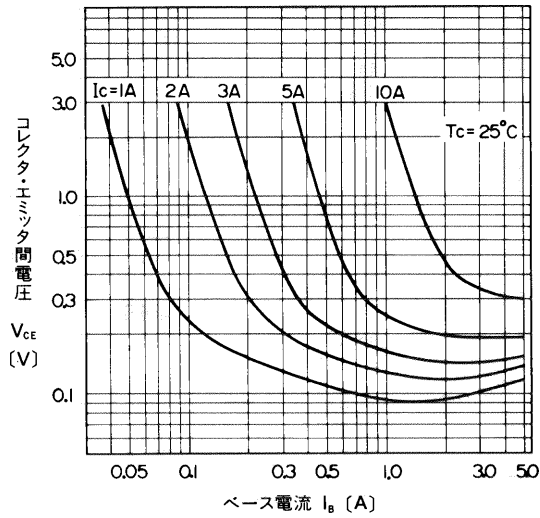
Electrical characteristics (T_c =25°C unless otherwise specified)

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	V _{CB0}	I _{CBO} = 1.0mA	500			V
Collector-Emitter voltage	V _{CE0(SUS)}	I _{CEO} = 200mA	400			V
Emitter-Base voltage	V _{EB0}	I _{EBO} = 1mA	7			V
Collector-Base leakage current	I _{CBO}	V _{CB0} = 500V			1.0	mA
D.C. current gain	h _{FE}	I _C = 6A, V _{CE} = 5V	10			
Collector-Emitter saturation voltage	V _{CE(Sat)}	I _C = 6A, I _B = 1.2A			1.0	V
Base-Emitter saturation voltage	V _{BE(Sat)}				1.5	V
Switching time	t _{on}	I _C = 7.5A, I _{B1} = +1.5A		0.25	0.5	μs
	t _{stg}	I _{B2} = -3.0A, R _L = 20Ω		1.0	1.5	μs
	t _f	PW = 20μs, Duty ≤ 2%		0.07	0.15	μs

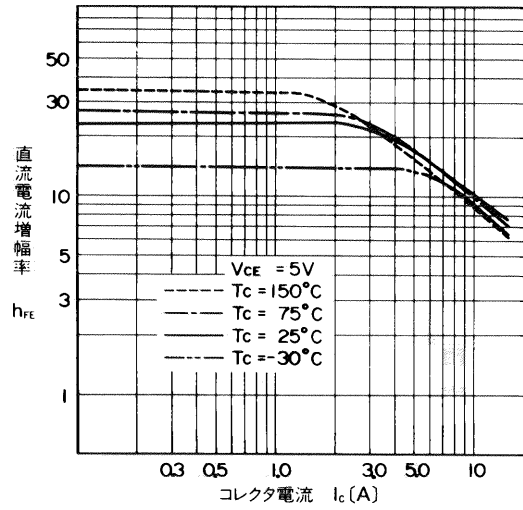
Thermal characteristics

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	R _{th(j-c)}	Junction to case			1.56	°C/W

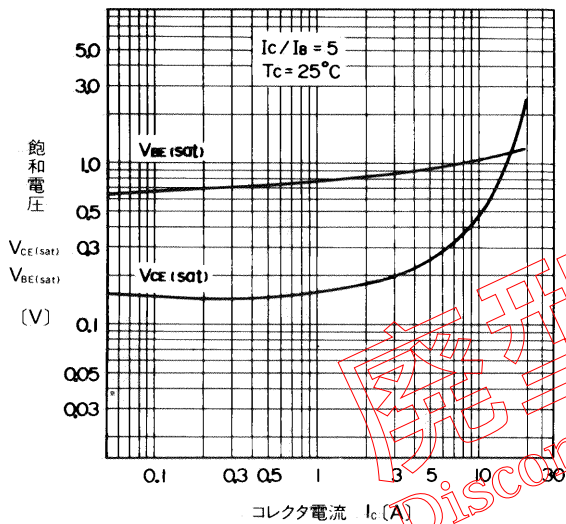
Characteristics



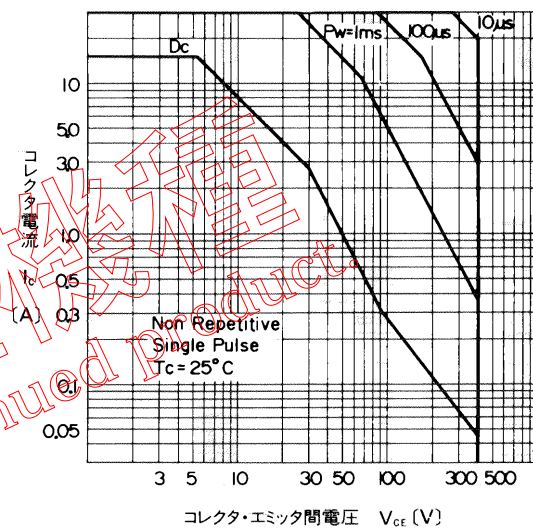
出力特性
Collector Output Characteristics



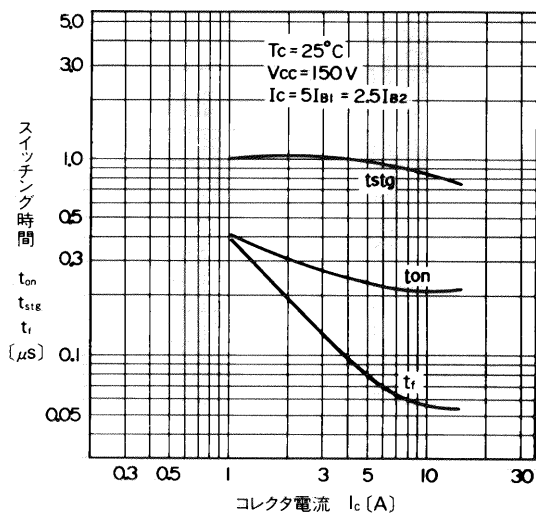
直流電流増幅率—コレクタ電流特性
DC Current Gain



飽和電圧—コレクタ電流特性
Base and Collector Saturation Voltage



安全動作領域特性
Safe Operating Area



スイッチング時間—コレクタ電流特性
Switching Time

スイッチングタイム測定回路
*) Switching Time Test Circuit

